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Research article

Sensitivity analysis of the complete electrode model for electrical impedance tomography

Marion Darbas¹, Jérémy Heleine², Renier Mendoza³ and Arriane Crystal Velasco^{3,4,*}

¹ LAGA CNRS UMR 7539, Université Sorbonne Paris Nord, Villetaneuse, France

² INRIA/Centre de mathématiques appliquées, École Polytechnique, Université Paris-Saclay, Palaiseau, France

³ Institute of Mathematics, University of the Philippines Diliman, Quezon City, Philippines

⁴ LAMFA CNRS UMR 7352, Université de Picardie Jules Verne, Amiens, France

* **Correspondence:** Email: acvelasco@math.upd.edu.ph.

Abstract: Electrical impedance tomography (EIT) is an imaging technique that reconstructs the conductivity distribution in the interior of an object using electrical measurements from the electrodes that are attached around the boundary. The Complete Electrode Model (CEM) accurately incorporates the electrode size, shape, and effective contact impedance into the forward problem for EIT. In this work, the effect of the conductivity distribution and the electrode contact impedance on the solution of the forward problem is addressed. In particular, the sensitivity of the electric potential with respect to a small-amplitude perturbation in the conductivity, and with respect to some defective electrodes is studied. The Gâteaux derivative is introduced as a tool for the sensitivity analysis and the Gâteaux differentiability of the electric potential with respect to the conductivity and to the contact impedance of the electrodes is proved. The derivative is then expressed as the unique solution to a variational problem and the discretization is performed with Finite Elements of type P1. Numerical simulations for different 2D and 3D configurations are presented. This study illustrates the impact of the presence of perturbations in the parameters of CEM on EIT measurements. Finally, the 2D inverse conductivity problem for EIT is numerically solved for some configurations and the results confirm the conclusions of the numerical sensitivity analysis.

Keywords: electrical impedance tomography; complete electrode model; sensitivity analysis; conductivity; contact impedance

Mathematics Subject Classification: 35R30, 65N30, 35B30

1. Introduction

Electrical properties such as the conductivity and the permittivity determine the behaviour of materials under the influence of external electric fields. Electrical Impedance Tomography (EIT) is a non invasive, radiation-free imaging technique which reconstructs the conductivity distribution inside an observation region. In practice, currents of prescribed magnitudes (typically in a frequency range from several hundred Hz to several MHz) are injected at electrodes placed on the boundary of the region. The current passes through the object and the resulting voltages are recorded. These measurements are the data needed to estimate the conductivity within the object. EIT is known to be a low cost and portable imaging modality. With these advantages, EIT is a thriving area of research due to the variety of possible applications (e.g. geophysical [47, 65], medical [3, 23, 26, 45, 54], and industrial [43, 49]).

In EIT systems, the quality and the accuracy of the measurements depend on many factors such as the configuration of the electrodes and the injected current distribution. The size, geometry, and location of the electrodes must be considered because they can affect the data needed for the reconstruction. The voltage loss due to the effective contact impedance, which is the thin resistive layer between the electrode and object, should also be taken into account to accurately measure the boundary voltages. In medical applications, the skin surface is prepared using a certain gel to lower and stabilize the contact impedance between the skin and the electrode. Moreover, current shunting effect through the pickup electrodes is a well-known problem in EIT systems. This phenomenon can be efficiently reduced by the geometry of the electrodes or by their separation. Also, boundary current distribution or current patterns affect the data since they are linearly related, given a fixed conductivity distribution [9]. It is essential to account all these parameters in order to produce more accurate data for the imaging [50].

Mathematically, EIT is divided into two parts: the forward problem and the inverse problem. The forward problem consists of finding the potential distribution inside the domain under examination and on its boundary from the knowledge of the electrical conductivity distribution in the domain and the injected surface current pattern. Solving the forward problem corresponds to the data acquisition. Thus, it is important to correctly model the electrodes on the boundary, their effects, and also the injected currents. For instance, we refer to the review article [4] and the references therein. The simplest forward model for EIT is the continuum model but it does not take into account the electrodes. The gap model attempts to represent the electrodes by points and approximates the current density by a nonzero constant at the surface of each electrode and zero in the gaps between the electrodes. The shunt model accounts the correct configuration of the electrodes but not the effective contact impedance. The Complete Electrode Model (CEM) successfully considers the geometry and location of the electrodes, and their shunting effects [11, 53]. Consequently, CEM is the most accurate and commonly used model for EIT. Many theoretical and numerical works have been devoted to the study of the CEM for EIT (see e.g. [6, 12, 16, 24, 25, 32, 33, 56]).

The EIT inverse problem is the recovery of the electrical conductivity distribution from the surface voltages and current density [4]. It is also known as Calderón's problem [8] which is a very ill-posed problem. An existence and uniqueness result is obtained by Kohn and Vogelius in [39], and they proved that the conductivity can be uniquely determined by the knowledge of the entire corresponding voltage-to-current or Dirichlet-to-Neumann map. However, only partial information on the Dirichlet-to-Neumann map is available in practical applications. In [34, 35, 38], the identifiability is proved if

only partial information is known. There is an extensive literature on the numerical resolution of the EIT inverse problem. Most of the methods are iterative and are based on deterministic or stochastic least squares reconstruction algorithms (e.g [15, 36, 42]). Several approaches have been considered for dealing with inaccuracy on the known boundary shape, and in particular the position uncertainty of the electrodes [15, 17, 18, 40, 41, 46, 52]. Simultaneous reconstruction of the conductivity distribution and the contact impedances has been proposed in [30, 59]. We can also cite direct inversion methods for EIT, in particular Calderón and D-bar (e.g [19, 28]). The use of neural networks and metaheuristic algorithms has been explored too (e.g. [27, 57, 60, 61, 63, 64]).

In this paper, we focus on the study of the CEM forward problem. The accuracy of the EIT reconstruction relies heavily on one of the associated forward model. We are interested in the sensitivity of the electric potential, and thus of the measurements, with respect to the conductivity or with respect to the contact impedance of the electrodes. This allows to measure the effect of uncertainty in both conductivity and contact impedance values on the CEM forward model. This also permits to understand the impact of possible perturbations of the conductivity (e.g. tumors or strokes in medical applications, or uncertainties in tissue conductivities) or of small changes in the impedance due to skin-to-electrode contact on the potential measurements. It can be viewed as a preliminary step for improving (direct or iterative) inversion methods. For the definition of sensitivity, several definitions exist in the literature. One can find works which are addressed by different communities (applied mathematics, bioengineering, physics, physiology, ...). The most simple and used is the numerical computation of the difference between measurements before and after a conductivity change in a known homogeneous medium. In [37], the authors observe numerically the sensitivity distribution of the measured impedance signal with respect to the conductivity distribution. Other works define the sensitivity as the fractional change of transfer impedance (ratio of the measured potential and the applied current) with respect to a change of a conductivity inside a region [2, 51]. In [2], the impact of the tissue conductivities and of the size of the electrodes on the performance of the EIT system in the thorax imaging is numerically analyzed. In [62], the authors consider absolute and relative sensitivities (defined by the difference between measured data with and without an anomaly in the conductivity) in a Frobenius-type norm. Furthermore, in [62], conformal maps are employed to introduce an analytic method to determine the sensitivity of boundary measurements to perturbations in conductivity for the CEM on circular domains. Based on this information, well-adapted discretizations of the conductivity space are proposed for the numerical solution of the inverse conductivity problem. The effect of the characteristics of the electrodes (contact impedance, area, boundary shape under the electrode) on the reconstructed EIT images has been studied in [7]. In the present work, an additional analysis tool to investigate the sensitivity of the solution of the CEM to small variations in conductivity or contact impedance is developed. We define in a rigorous way the mathematical setting of the sensitivity equations and we address both theoretical and numerical aspects.

The paper is organized as follows. In Section 2, we introduce the CEM. In Section 3, we present a sensitivity analysis of the CEM. In Section 4, we address the discretization of the CEM and the resulting variational problems for the sensitivity equations using Lagrange finite elements. Section 5 is devoted to the numerical part of the sensitivity analysis. Various two- and three-dimensional numerical simulations, and discussions are provided. The end of Section 5 deals with the numerical solution of the 2D EIT inverse conductivity problem for several configurations. Finally, we give some conclusions and perspectives in the last section.

2. The forward problem: the Complete Electrode Model

Let Ω be a bounded simply connected domain in \mathbb{R}^d , $d = 2, 3$, with a smooth boundary $\partial\Omega$. In the low frequency range under consideration in EIT experiments, the electromagnetic field satisfies the quasi-static Maxwell equations where the time derivatives are neglected [4, 10]. This yields the following form of Maxwell's equations in terms of the electric field \mathbf{E} and the magnetic field \mathbf{H} ,

$$\nabla \cdot (\varepsilon \mathbf{E}) = \rho, \quad (2.1a)$$

$$\nabla \cdot (\mu \mathbf{H}) = 0, \quad (2.1b)$$

$$\nabla \times \mathbf{E} = 0, \quad (2.1c)$$

$$\nabla \times \mathbf{H} = \mathbf{J}. \quad (2.1d)$$

Here, ρ is the charge density, ε and μ are the electric permittivity and magnetic permeability, respectively, and \mathbf{J} is the electric current density. Moreover, given the conductivity distribution σ in the domain Ω , Ohm's law gives

$$\mathbf{J} = \sigma \mathbf{E}. \quad (2.2)$$

It follows from (2.1c) that the electric field \mathbf{E} derives from an electric (scalar) potential u , i.e.

$$\mathbf{E} = -\nabla u. \quad (2.3)$$

Taking the divergence of (2.1d), and using (2.2) and (2.3) yields the following elliptic equation for the electrical potential u in Ω

$$\nabla \cdot (\sigma \nabla u) = 0. \quad (2.4)$$

The conductivity $\sigma \in L^\infty(\Omega)$ is assumed to satisfy

$$\sigma_{\min} \leq \sigma(\mathbf{x}) \leq \sigma_{\max}, \quad \mathbf{x} \in \Omega, \quad (2.5)$$

for some constants $0 < \sigma_{\min} \leq \sigma_{\max} < +\infty$. Let $\mathbf{n} := \mathbf{n}(\mathbf{x})$ be the exterior unit normal of $\partial\Omega$. For a known conductivity distribution σ in Ω and boundary data U (voltage) or I (current density), the equation (2.4) together with either a Dirichlet boundary condition

$$u = U, \text{ on } \Gamma$$

or a Neumann boundary condition

$$\sigma \partial_{\mathbf{n}} u = I, \text{ on } \partial\Omega, \text{ with } \int_{\partial\Omega} I \, ds = 0,$$

is called the *continuum model* for EIT.

In experiments, a finite number of surface electrodes, on which currents of prescribed magnitudes are injected and voltages are recorded, are attached to the boundary. Different electrode models have been proposed and studied but the most accurate mathematical model for real-life EIT is the Complete Electrode Model (CEM) [11, 53]. The electrodes are modeled by L subdomains $\{e_\ell\}_{\ell=1}^L$ on $\partial\Omega$ at which we inject current patterns $I = (I_\ell)_{\ell=1}^L \in \mathbb{R}^L$ and measure the resulting potential vectors $U = (U_\ell)_{\ell=1}^L \in$

\mathbb{R}^L . The electrodes are also assumed to be well-separated, i.e., $\bar{e}_m \cap \bar{e}_\ell = \emptyset$, if $m \neq \ell$, and we set $\Gamma_e := \bigcup_{\ell=1}^L e_\ell$. The current pattern I belongs to the mean-free subspace

$$\mathbb{R}_\diamond^L := \left\{ W = (W_\ell)_{\ell=1}^L \in \mathbb{R}^L \left| \sum_{\ell=1}^L W_\ell = 0 \right. \right\}$$

due to conservation of electric charge. Each electrode e_ℓ is considered to be an open subset of the boundary $\partial\Omega$ with positive surface measure. Electrodes are assumed to be perfect conductors (i.e. the potential is constant on each electrode). This is the so-called shunting effect. Furthermore, effective contact impedance, which is the thin, highly-resistive layer at the contact of e_ℓ with $\partial\Omega$, is accounted and denoted by $Z = (z_\ell)_{\ell=1}^L \in \mathbb{R}^L$ that is assumed to satisfy

$$z_\ell > z_{\min}, \quad (2.6)$$

with z_{\min} a positive constant. According to Ohm's law, this effect causes a voltage drop $z_\ell \sigma \partial_{\mathbf{n}} u$ and is modeled by a Robin-type boundary condition [53]

$$u + z_\ell \sigma \partial_{\mathbf{n}} u = U_\ell, \quad \text{on } e_\ell, \quad \ell = 1, \dots, L. \quad (2.7)$$

Now, assuming that the current flowing on each electrode is equal to the current injected and that there is no current flow on the parts of the boundary where there is no electrode, we have

$$\int_{e_\ell} \sigma \partial_{\mathbf{n}} u \, ds = I_\ell, \quad \ell = 1, \dots, L, \quad (2.8)$$

$$\sigma \partial_{\mathbf{n}} u = 0, \quad \text{on } \partial\Omega \setminus \Gamma_e. \quad (2.9)$$

The CEM is the following forward problem for EIT: given a current pattern $I = (I_\ell)_{\ell=1}^L \in \mathbb{R}_\diamond^L$, a conductivity distribution σ satisfying (2.5) and contact impedances $Z = (z_\ell)_{\ell=1}^L \in \mathbb{R}^L$, find the pair $(u, U) \in H := H^1(\Omega) \oplus \mathbb{R}_\diamond^L$ solution to the boundary-value problem (2.4)-(2.7)-(2.8)-(2.9). Existence of solution is ensured by the condition

$$\sum_{\ell=1}^L I_\ell = 0 \quad (2.10)$$

whereas the uniqueness is proved by assuming

$$\sum_{\ell=1}^L U_\ell = 0. \quad (2.11)$$

The variational formulation of the CEM forward problem reads: Find $(u, U) \in H$ such that

$$B_\sigma((u, U), (w, W)) = \sum_{\ell=1}^L I_\ell W_\ell, \quad (2.12)$$

for all $(w, W) \in H$, where the bilinear form $B_\sigma : H \times H \rightarrow \mathbb{R}$ is defined by

$$B_\sigma((u, U), (w, W)) := \int_{\Omega} \sigma \nabla u \cdot \nabla w \, dx + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} (u - U_\ell)(w - W_\ell) \, ds. \quad (2.13)$$

Existence and uniqueness of solution $(u, U) \in H$ has been proved using the Lax-Milgram theorem in [53]. Indeed, the bilinear form B_σ is bounded and coercive on H with respect to norm $\|\cdot\|_H$ given

$$\text{by } \|(u, U)\|_H^2 := \|u\|_{H^1(\Omega)}^2 + \sum_{\ell=1}^L U_\ell^2.$$

Remark 1. *The proof is based on the fact that the space $(H, \|\cdot\|_H)$ and the quotient space $(H^1(\Omega) \oplus \mathbb{R}^L)/\mathbb{R}$ equipped with the following norm*

$$\|(u, U)\|_* = \left(\|\nabla u\|_{L^2(\Omega)}^2 + \sum_{\ell=1}^L \int_{e_\ell} |u - U_\ell|^2 dS \right)^{1/2} \quad (2.14)$$

are norm-equivalent [53].

In the medical applications that we have in mind, the computational domain Ω may represent a head model or a torso and is composed of different tissues or organs (see Section 5). In this context, we consider a partition of Ω into M open disjoint subdomains $(\Omega_i)_{i=1,\dots,M}$, $\Omega_i \subset \Omega$, with smooth surfaces such that $\bar{\Omega} = \bigcup_{i=1}^M \bar{\Omega}_i$. We require that $\sigma|_{\Omega_i} \in C(\bar{\Omega}_i)$, $1 \leq i \leq M$, and assumption (2.5) to prove the existence and uniqueness of a weak solution $(u, U) \in H$ for the CEM problem. The result is again a consequence of the Lax–Milgram theorem [53].

3. Sensitivity analysis

Sensitivity indicates the behavior of the potential when there is a slight variation of physical parameters. Here, we are interested in the sensitivity with respect to the conductivity and with respect to the contact impedance of the electrodes, in order to understand the effect of uncertainty in their values on the CEM forward model. This permits to understand the impact of possible perturbations of the conductivity or small electrode defects on the potential measurements. Mathematically, a rigorous way to describe sensitivity is given by Gâteaux differentiability which expresses a weak concept of derivative.

Definition 1. *Let $w : X \rightarrow Y$ be an application between two Banach spaces X and Y . Let $O \subset X$ be an open set. The directional derivative $D_\mu w(p)$ of w at $p \in O$ in the direction $\mu \in X$ is defined by*

$$D_\mu w(p) = \lim_{h \rightarrow 0} \frac{w(p + \mu h) - w(p)}{h}$$

if the limit exists. If $D_\mu w(p)$ exists for any direction $\mu \in X$ and if the map $\mu \mapsto D_\mu w(p)$ is linear continuous from X to Y , w is said to be Gâteaux differentiable at p .

3.1. Sensitivity analysis with respect to a perturbation of the conductivity

We introduce the (open) space of admissible conductivities

$$\mathcal{P}_{\text{adm}} := \{\sigma \in L^\infty(\Omega) | \sigma_{\min} < \sigma < \sigma_{\max}\}.$$

We set $(u, U) := (u(\cdot, \sigma), U(\sigma))$ as the solution of the variational formulation (2.12). Problem (2.12) with conductivity $\sigma \in \mathcal{P}_{\text{adm}}$ admits a unique solution $(u, U) \in H$. The aim is to prove differentiability

of (u, U) with respect to σ and to identify its derivative in a given direction μ . We consider a direction $\mu \in L^\infty(\Omega)$ with $\|\mu\|_\infty = 1$ such that $\sigma + h\mu \in \mathcal{P}_{\text{adm}}$ for any $h \in [-h_0, h_0]$, $h_0 > 0$. The solution of the perturbed CEM forward problem with conductivity $\sigma + h\mu$ is $(u^h, U^h) := (u(\cdot, \sigma + h\mu), U(\sigma + h\mu)) \in H$. The associated variational formulation reads: find $(u^h, U^h) \in H$ such that

$$B_{\sigma+h\mu}((u^h, U^h), (w, W)) = \sum_{\ell=1}^L I_\ell W_\ell, \quad (3.1)$$

for all $(w, W) \in H$, where the bilinear form is defined by

$$B_{\sigma+h\mu}((u^h, U^h), (w, W)) := \int_{\Omega} (\sigma + h\mu) \nabla u^h \cdot \nabla w \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} (u^h - U_\ell^h)(w - W_\ell) \, ds. \quad (3.2)$$

In the sequel, we write $a \lesssim b$ if there is a constant $C > 0$ independent from the quantities a and b such that $a \leq Cb$. We have the following preliminary lemma.

Lemma 1. *Let $\sigma \in \mathcal{P}_{\text{adm}}$ and $h_0 > 0$ such that $\sigma + h\mu \in \mathcal{P}_{\text{adm}}$ for any $h \in [-h_0, h_0]$ and any $\mu \in L^\infty(\Omega)$ with $\|\mu\|_{L^\infty(\Omega)} = 1$. Let (u, U) and (u^h, U^h) be the respective solutions in H of the variational problems (2.12) and (3.1) for all $(w, W) \in H$. Then, we have the following estimate*

$$\|\nabla(u^h - u)\|_{L^2(\Omega)} \lesssim h\|\mu\|_{L^\infty(\Omega)}.$$

Proof. Subtracting (2.12) from (3.1) leads to

$$B_\sigma((u^h - u, U^h - U), (w, W)) = -h \int_{\Omega} \mu \nabla u^h \cdot \nabla w \, d\mathbf{x}, \quad \forall (w, W) \in H. \quad (3.3)$$

Taking $(w, W) = (u^h - u, U^h - U)$ and using the Cauchy-Schwarz inequality, we get

$$|B_\sigma((u^h - u, U^h - U), (u^h - u, U^h - U))| \leq h\|\mu\|_{L^\infty(\Omega)} \|\nabla u^h\|_{L^2(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)}. \quad (3.4)$$

Considering both the coercivity of B_σ on H and the equivalence of the norms $\|\cdot\|_H$ and $\|\cdot\|_*$ (see Remark 1) in (3.4) leads to

$$\|(u^h - u, U^h - U)\|_*^2 \lesssim h\|\mu\|_{L^\infty(\Omega)} \|\nabla u^h\|_{L^2(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)}.$$

Furthermore, the definition of the $\|\cdot\|_*$ -norm gives

$$\|\nabla(u^h - u)\|_{L^2(\Omega)} \lesssim \|(u^h - u, U^h - U)\|_*.$$

Thus we have

$$\|(u^h - u, U^h - U)\|_*^2 \lesssim h\|\mu\|_{L^\infty(\Omega)} \|\nabla u^h\|_{L^2(\Omega)} \|(u^h - u, U^h - U)\|_*. \quad (3.5)$$

We study in the same way the variational problem (3.1), that is, we again use the coercivity of $B_{\sigma+h\mu}$, the definition of the $\|\cdot\|_*$ -norm, and the equivalence of the norms $\|\cdot\|_H$ and $\|\cdot\|_*$ to prove that

$$\|\nabla u^h\|_{L^2(\Omega)} \leq C(\sigma_{\min})$$

with $C(\sigma_{\min})$ a positive constant independent from h . Hence, (3.5) reads

$$\|(u^h - u, U^h - U)\|_* \lesssim h\|\mu\|_{L^\infty(\Omega)}$$

and finally, applying again the definition of the norm $\|\cdot\|_*$, we conclude

$$\|\nabla(u^h - u)\|_{L^2(\Omega)} \lesssim h\|\mu\|_{L^\infty(\Omega)}.$$

□

Proposition 1. *Let $\sigma \in \mathcal{P}_{adm}$ and $h_0 > 0$ such that $\sigma + h\mu \in \mathcal{P}_{adm}$ for any $h \in [-h_0, h_0]$ and $\mu \in L^\infty(\Omega)$ with $\|\mu\|_{L^\infty(\Omega)} = 1$. Then the solution $(u(\cdot, \sigma), U(\sigma))$ of (2.12) is Gâteaux differentiable with respect to σ . Moreover, the Gâteaux derivative of (u, U) in the direction $\mu \in L^\infty(\Omega)$ is the unique solution of the following variational problem: find $(u^1, U^1) \in H$ such that*

$$B_\sigma((u^1, U^1), (w, W)) = - \int_\Omega \mu \nabla u \cdot \nabla w \, d\mathbf{x}. \quad (3.6)$$

for all $(w, W) \in H$.

Proof. Let us introduce the differential quotients

$$u^{1,h} := \frac{u^h - u}{h} \text{ and } U^{1,h} := \frac{U^h - U}{h}.$$

Subtracting (2.12) from (3.1) and dividing by h leads to

$$B_\sigma((u^{1,h}, U^{1,h}), (w, W)) = - \int_\Omega \mu \nabla u^h \cdot \nabla w \, d\mathbf{x}, \quad \forall (w, W) \in H. \quad (3.7)$$

We compare the previous formulation (3.7) with the variational formulation (3.6)

$$\int_\Omega \nabla(u^{1,h} - u^1) \cdot \nabla w \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} ((u^{1,h} - u^1) - (U_\ell^{1,h} - U_\ell^1))(w - W_\ell) \, ds = - \int_\Omega \mu \nabla(u^h - u) \cdot \nabla w \, d\mathbf{x}.$$

We take $(w, W) = (u^{1,h} - u^1, U^{1,h} - U^1)$ and get

$$B_\sigma((u^{1,h} - u^1, U^{1,h} - U^1), (u^{1,h} - u^1, U^{1,h} - U^1)) \leq \|\mu\|_{L^\infty(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)} \|\nabla(u^{1,h} - u^1)\|_{L^2(\Omega)}.$$

The coercivity of B_σ on H and the equivalence of the norms $\|\cdot\|_H$ and $\|\cdot\|_*$ (see (2.14)) give

$$\|(u^{1,h} - u^1, U^{1,h} - U^1)\|_*^2 \lesssim \|\mu\|_{L^\infty(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)} \|\nabla(u^{1,h} - u^1)\|_{L^2(\Omega)}$$

and the definition of the $\|\cdot\|_*$ -norm leads to

$$\|(u^{1,h} - u^1, U^{1,h} - U^1)\|_*^2 \lesssim \|\mu\|_{L^\infty(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)} \|(u^{1,h} - u^1, U^{1,h} - U^1)\|_*.$$

Hence, we obtain

$$\|(u^{1,h} - u^1, U^{1,h} - U^1)\|_* \lesssim \|\mu\|_{L^\infty(\Omega)} \|\nabla(u^h - u)\|_{L^2(\Omega)}. \quad (3.8)$$

Finally, from Lemma 1, (3.8) reads

$$\|(u^{1,h} - u^1, U^{1,h} - U^1)\|_* \lesssim h \|\mu\|_{L^\infty(\Omega)}^2.$$

This proves the strong convergence of the sequence $(u^{1,h}, U^{1,h})_h$ to (u^1, U^1) in H .

Now it remains to show that the map $\mu \mapsto (u^1, U^1)$ is linear continuous from $L^\infty(\Omega)$ to H . For fixed μ , the derivative is defined by the solution of (3.6) and the right-hand side of (3.6) is linear in μ . The continuity of the linear application $\mu \mapsto (u^1, U^1)$ follows from the following estimate: taking $(w, W) = (u^1, U^1)$ in (3.6), we get

$$\|(u^1, U^1)\|_* \lesssim \|\mu\|_{L^\infty(\Omega)}.$$

This yields the continuity of the directional derivative with respect to μ and proves that $(u(\cdot, \sigma), U(\sigma))$ is Gâteaux differentiable with respect to the conductivity σ . \square

The derivative (u^1, U^1) of the potential (u, U) with respect to the conductivity σ in the direction μ is solution of the following boundary value problem

$$\begin{cases} -\nabla \cdot (\sigma \nabla u^1) = \nabla \cdot (\mu \nabla u) & \text{in } \Omega, \\ u^1 + z_\ell \sigma \partial_{\mathbf{n}} u^1 = -z_\ell \mu \partial_{\mathbf{n}} u + U_\ell^1 & \text{on } e_\ell, \ell = 1, \dots, L, \\ \int_{e_\ell} \sigma \partial_{\mathbf{n}} u^1 ds = - \int_{e_\ell} \mu \partial_{\mathbf{n}} u ds & \ell = 1, \dots, L, \\ \sigma \partial_{\mathbf{n}} u^1 = -\mu \partial_{\mathbf{n}} u & \text{on } \partial\Omega \setminus \Gamma_e, \end{cases} \quad (3.9)$$

where u is the solution of the unperturbed problem, i.e., it satisfies $\nabla \cdot (\sigma \nabla u) = 0$. Formally, consider a perturbation of σ of the form $\sigma + \mu h$ for fixed μ . The potential u^h is the solution of the perturbed equation $\nabla \cdot ((\sigma + \mu h) \nabla u) = 0$. Subtracting the above equations and dividing by h yields

$$-\nabla \cdot \left(\sigma \nabla \left(\frac{u^h - u}{h} \right) \right) = \nabla \cdot (\mu \nabla u).$$

At the limit $h \rightarrow 0$, we get that the sensitivity u^1 satisfies the first equation of (3.9). The different boundary equations can be obtained in a similar way. The variational formulation of the problem (3.9) is given by (3.6).

Remark 2. *The Fréchet differentiability of the map $(\sigma, y) \mapsto (u, U)$, where $y := 1/Z$, has been proved by Kaipio et al (see [36] Theorem 2.3). Indeed, it implies the Gâteaux differentiability of the potential with respect to both the conductivity σ and the inverse $1/Z$ of contact impedance. Nevertheless, the sensitivity analysis of the forward CEM needs only the existence of all the directional derivatives of (u, U) . We have detailed the proof of Proposition 1 for readers who want to deepen the concept of sensitivity analysis for PDEs. Furthermore, we propose a proof for the Gâteaux differentiability of the potential with respect to Z (and not to $1/Z$ as in [36]) and give an expression of the directional derivatives of (u, U) in that case (see Section 3.2 Proposition 2 and Appendix).*

3.2. Sensitivity analysis with respect to a perturbation of the contact impedance

We introduce the set of admissible contact impedances

$$\mathcal{Z}_{\text{adm}} := \{Z \in \mathbb{R}^L \mid z_{\min} < z_\ell < z_{\max}\},$$

with $0 < z_{\min} \leq z_{\max} < +\infty$. Similar arguments to those in the proof of Proposition 1 lead to the following result.

Proposition 2. Let I be a fixed current pattern and σ a known conductivity distribution satisfying (2.5). Let $Z \in \mathcal{Z}_{adm}$ such that $Z + \eta h \in \mathcal{Z}_{adm}$ for any $h \in [-h_0, h_0]$ and $\eta \in \mathbb{R}^L$. Then the solution (u, U) of (2.12) is Gâteaux differentiable with respect to Z . Furthermore, its Gâteaux derivative in the direction η is the unique solution of the following variational problem: find $(u^2, U^2) \in H$ such that

$$B_\sigma((u^2, U^2), (w, W)) = \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} (u - U_\ell)(w - W_\ell) ds \quad (3.10)$$

for all $(w, W) \in H$.

The full proof of Proposition 2 is given in the Appendix. The derivative (u^2, U^2) of the potential (u, U) with respect to the contact impedance Z in the direction η is solution of the following boundary value problem

$$\begin{cases} \nabla \cdot (\sigma \nabla u^2) = 0 & \text{in } \Omega \\ u^2 + z_\ell \sigma \partial_{\mathbf{n}} u^2 = -\eta_\ell \sigma \partial_{\mathbf{n}} u + U_\ell^2 & \text{on } e_\ell, \ell = 1, \dots, L, \\ \int_{e_\ell} \sigma \partial_{\mathbf{n}} u^2 ds = 0 & \ell = 1, \dots, L, \\ \sigma \partial_{\mathbf{n}} u^2 = 0 & \text{on } \partial\Omega \setminus \Gamma_e. \end{cases} \quad (3.11)$$

The variational formulation of the problem (3.11) is given by (3.10) subject to the above boundary conditions.

Remark 3. Using the same arguments as in the proofs of Propositions 1 and 2, we can show that (u, U) is Gâteaux differentiable with respect to both σ and Z , simultaneously. The derivative (u^3, U^3) is the unique element in H satisfying

$$B_\sigma((u^3, U^3), (w, W)) = - \int_{\Omega} \mu \nabla u \cdot \nabla w \, d\mathbf{x} + \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} (u - U_\ell)(w - W_\ell) ds$$

for all $(w, W) \in H$. We recognize that

$$(u^3, U^3) = (u^1, U^1) + (u^2, U^2)$$

where (u^1, U^1) and (u^2, U^2) are the respective unique solutions of problems (3.7) and (3.10). It seems that it is more interesting to study the sensitivity with respect to σ and Z separately to better understand the influences of perturbations in each parameter on the CEM.

4. Finite element formulation

In this section, we address the discretization of the different variational problems. We use the finite element method (FEM) to compute an approximate solution of the CEM and the sensitivity equations (3.6) and (3.10).

4.1. Discretization for the CEM forward problem

We consider a triangular (respectively tetrahedral) mesh \mathcal{T}_h for 2D (respectively 3D) geometries Ω . For any mesh parameter h , we denote by Ω_h the discrete domain and by N the number of nodes. On \mathcal{T}_h ,

we introduce X_h the standard vector space of Lagrange finite elements of type P1. The approximation $u_h \in X_h$ of the electric potential u is of the form

$$u_h(\mathbf{x}) = \sum_{j=1}^N v_j \varphi_j(\mathbf{x}), \quad \mathbf{x} \in \Omega_h, \quad (4.1)$$

where the functions φ_j are linear basis functions. We focus on the numerical implementation proposed in [36]. We explain here the main lines of the approach.

To impose the uniqueness condition (2.11), a different representation of the voltage U is introduced. Define a set of vectors $\phi_\ell \in \mathbb{R}^L$, $\ell = 1, \dots, L-1$, by $\phi_1 = (1, -1, 0, \dots, 0)^T$, $\phi_2 = (1, 0, -1, \dots, 0)^T$, \dots , $\phi_{L-1} = (1, 0, \dots, -1)^T$. The approximation U_h of U is expressed as

$$U_h = \sum_{k=1}^{L-1} \beta_k \phi_k, \quad (4.2)$$

where $\beta_k \in \mathbb{R}$, $k = 1, \dots, L-1$. Let $\beta = (\beta_k)^T \in \mathbb{R}^{L-1}$ and define the matrix $P = (\phi_1 | \dots | \phi_{L-1}) \in \mathbb{R}^{L \times (L-1)}$. Thus, the voltages U_h are determined by

$$U_h = P\beta. \quad (4.3)$$

Consider the test functions $(w, W) = (\varphi_i, \mathbf{0})$. Substituting (4.1)-(4.2) to (2.12), we get for each $i = 1, \dots, N$

$$\sum_{j=1}^N v_j \int_{\Omega_h} \sigma \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} \left(\sum_{j=1}^N v_j \varphi_j - \sum_{k=1}^{L-1} \beta_k \phi_k \right) \varphi_i \, ds = 0.$$

We get the following linear system

$$\begin{bmatrix} S + M & C \end{bmatrix} \begin{bmatrix} v \\ \beta \end{bmatrix} = \begin{bmatrix} 0 \\ \mathbf{0}_{\mathbb{R}^N} \end{bmatrix}, \quad (4.4)$$

with $v = (v_j)_{j=1}^N \in \mathbb{R}^N$, $S = (S_{ij})$, $M = (M_{ij}) \in \mathbb{R}^{N \times N}$ of respective coefficients $S_{ij} = \int_{\Omega_h} \sigma \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x}$

and $M_{ij} = \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} \varphi_j \varphi_i \, ds$, and $C = (C_{i\ell}) \in \mathbb{R}^{N \times (L-1)}$ with $C_{i\ell} = -\left(\frac{1}{z_1} \int_{e_1} \varphi_i \, ds - \frac{1}{z_{\ell+1}} \int_{e_{\ell+1}} \varphi_i \, ds \right)$.

Furthermore, the conditions (2.7) and (2.8) give

$$\frac{1}{z_\ell} \int_{e_\ell} (U_\ell - u) \, ds = I_\ell, \quad \ell = 1, 2, \dots, L. \quad (4.5)$$

Then, the approximations (4.1) and (4.2) are used in (4.5). In order to obtain a symmetric system of equations in the end, the number of equations above should be reduced to $L-1$ which is done by subtracting from I_1 all the remaining current values I_ℓ , $\ell = 2, 3, \dots, L$. We have

$$\begin{aligned} I_1 - I_2 &= \sum_{j=1}^N \left(-\frac{1}{z_1} \int_{e_1} \varphi_j \, ds + \frac{1}{z_2} \int_{e_2} \varphi_j \, ds \right) u_j^h + \left(\frac{1}{z_1} \int_{e_1} ds + \frac{1}{z_2} \int_{e_2} ds \right) \beta_1 \\ &\quad + \sum_{\ell=1, \ell \neq 1}^{L-1} \left(\frac{1}{z_1} \int_{e_1} ds \right) \beta_\ell \end{aligned}$$

$$\begin{aligned}
I_1 - I_3 &= \sum_{j=1}^N \left(-\frac{1}{z_1} \int_{e_1} \varphi_j ds + \frac{1}{z_3} \int_{e_3} \varphi_j ds \right) u_j^h + \left(\frac{1}{z_1} \int_{e_1} ds + \frac{1}{z_3} \int_{e_3} ds \right) \beta_2 \\
&\quad + \sum_{\ell=1, \ell \neq 2}^{L-1} \left(\frac{1}{z_1} \int_{e_1} ds \right) \beta_\ell \\
&\quad \vdots \\
I_1 - I_L &= \sum_{j=1}^N \left(-\frac{1}{z_1} \int_{e_1} \varphi_j ds + \frac{1}{z_L} \int_{e_L} \varphi_j ds \right) u_j^h + \left(\frac{1}{z_1} \int_{e_1} ds + \frac{1}{z_L} \int_{e_L} ds \right) \beta_{L-1} \\
&\quad + \sum_{\ell=1, \ell \neq L-1}^{L-1} \left(\frac{1}{z_1} \int_{e_1} ds \right) \beta_\ell.
\end{aligned}$$

Note that $\int_{e_\ell} ds = |e_\ell|$, where $|e_\ell|$ is the length (respectively the area) of the electrode in the two-dimensional (respectively in the three-dimensional) case and that $P^T I = (I_1 - I_2, I_1 - I_3, \dots, I_1 - I_L)^T$. Therefore, we have the following matrix form of the $L - 1$ equations equivalent to (4.5)

$$\begin{bmatrix} C^T & G \end{bmatrix} \begin{bmatrix} v \\ \beta \end{bmatrix} = \begin{bmatrix} P^T I \end{bmatrix}, \quad (4.6)$$

where $G \in \mathbb{R}^{(L-1) \times (L-1)}$ is given by

$$G_{ik} = \begin{cases} \frac{|e_1|}{z_1}, & i \neq k \\ \frac{|e_1|}{z_1} + \frac{|e_{k+1}|}{z_{k+1}}, & i = k. \end{cases}$$

Finally, an approximate solution of the CEM is obtained by solving the following linear system of size $N + L - 1$

$$\begin{bmatrix} S + M & C \\ C^T & G \end{bmatrix} \begin{bmatrix} v \\ \beta \end{bmatrix} = \begin{bmatrix} \mathbf{0}_{\mathbb{R}^N} \\ P^T I \end{bmatrix}. \quad (4.7)$$

The vector $v = (v_j)_j \in \mathbb{R}^N$ gives the approximation u_h of the potential u , and β leads to the calculation of the voltages U_h at the electrodes using (4.3).

4.2. Discretization for the sensitivity equation with respect to the conductivity

We again apply the approach of Kaipio *et al* [36] described previously. The approximation u_h^1 of the sensitivity u^1 is defined by

$$u_h^1(\mathbf{x}) = \sum_{j=1}^N v_j^1 \varphi_j(\mathbf{x}) \quad (4.8)$$

where v_j^1 is the approximated value of u^1 at the j th node. To ensure that the potential U^1 satisfy the condition (2.11), we search the approximation U_h^1 of U^1 under the form

$$U_h^1 = \sum_{k=1}^{L-1} \beta_k^1 \phi_k, \quad (4.9)$$

with $U_h^1 = P\beta^1$ and $\beta^1 = (\beta_k^1)^T \in \mathbb{R}^{L-1}$ (see (4.3)).

We set the test functions $(w, W) = (\varphi_i, \mathbf{0})$. We substitute (4.1), (4.8) and (4.9) to (3.6), and we get for $i = 1, \dots, N$

$$\sum_{j=1}^N v_j^1 \int_{\Omega_h} \sigma \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} \left(\sum_{j=1}^N v_j^1 \varphi_j - \sum_{k=1}^{L-1} \beta_k^1 \phi_k \right) \varphi_i \, ds = - \sum_{j=1}^N v_j \int_{\Omega_h} \mu \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x}, \quad (4.10)$$

where $v = (v_j)_{j=1}^N$ represents the approximation of the solution u of the unperturbed CEM (2.4)-(2.7)-(2.8)-(2.9). Furthermore, from the boundary conditions in (3.9), we deduce

$$\frac{1}{z_\ell} \int_{e_\ell} (U_\ell^1 - u^1) \, ds = 0 \quad \ell = 1, 2, \dots, L. \quad (4.11)$$

We use the same method which is presented previously to treat (4.5). Finally, we obtain the following linear system of size $N + L - 1$

$$\begin{bmatrix} S + M & C \\ C^T & G \end{bmatrix} \begin{bmatrix} v^1 \\ \beta^1 \end{bmatrix} = \begin{bmatrix} Fv \\ \mathbf{0}_{\mathbb{R}^{L-1}} \end{bmatrix}, \quad (4.12)$$

where $v^1 = (v_j^1)_{j=1}^N$, $F = (F_{ij}) \in \mathbb{R}^{N \times N}$ with coefficients $F_{ij} = - \int_{\Omega_h} \mu \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x}$. The vector v is computed using the resolution of the linear system (4.7).

4.3. Discretization for the sensitivity equation with respect to the contact impedance

The approximation of the potential (u^2, U^2) is given respectively by

$$u_h^2(\mathbf{x}) = \sum_{j=1}^N v_j^2 \varphi_j(\mathbf{x}), \quad (4.13)$$

where v_j^2 is the approximation of the value of u^2 at the j th node, and

$$U_h^2 = \sum_{k=1}^{L-1} \beta_k^2 \phi_k, \quad (4.14)$$

with $U_h^2 = P\beta^2$ and $\beta^2 = (\beta_k^2)^T \in \mathbb{R}^{L-1}$. The approximations (4.13) and (4.14), and the choice of test functions $(w, W) = (\varphi_i, \mathbf{0})$ in (3.10) give for $i = 1, \dots, N$

$$\begin{aligned} \sum_{j=1}^N v_j^2 \int_{\Omega_h} \sigma \nabla \varphi_j \cdot \nabla \varphi_i \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell} \int_{e_\ell} \left(\sum_{j=1}^N v_j^2 \varphi_j - \sum_{k=1}^{L-1} \beta_k^2 \phi_k \right) \varphi_i \, ds \\ = \sum_{j=1}^N v_j \left(\sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell} \int_{e_\ell} \varphi_i \varphi_j \, ds \right) - \sum_{\ell=1}^L U_h^\ell \left(\int_{e_\ell} \frac{\eta_\ell}{z_\ell} \varphi_i \, ds \right), \end{aligned} \quad (4.15)$$

where $v = (v_j)_{j=1}^N \in \mathbb{R}^N$ is the approximation of the potential u of the unperturbed CEM (2.4)-(2.7)-(2.8)-(2.9) and $U_h = (U_h^\ell) \in \mathbb{R}^L$ is obtained from (4.2). The boundary conditions in (3.11) lead to the relation

$$\frac{1}{z_\ell} \int_{e_\ell} (U_\ell^2 - u^2) \, ds = \frac{\eta_\ell}{z_\ell}, \quad \ell = 1, 2, \dots, L. \quad (4.16)$$

We get the following linear system of size $N + L - 1$

$$\begin{bmatrix} S + M & C \\ C^T & G \end{bmatrix} \begin{bmatrix} v^2 \\ \beta^2 \end{bmatrix} = \begin{bmatrix} Qv + DU_h \\ P^T I \end{bmatrix}, \quad (4.17)$$

where $v^2 = (v_j^2)_{j=1}^N \in \mathbb{R}^N$, $Q = (Q_{ij}) \in \mathbb{R}^{N \times N}$ with $Q_{ij} = \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} \varphi_i \varphi_j ds$, $D = (D_{i\ell}) \in \mathbb{R}^{N \times L}$ with $D_{ij} = -\frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} \varphi_i ds$, and $I = \left(\frac{\eta_\ell I_\ell}{z_\ell}\right)_\ell \in \mathbb{R}^L$.

5. Numerical sensitivity analysis

We study numerically how a slight variation of the conductivity or of the contact impedance of the electrodes affect the electric potential u and the EIT measurements $U \in \mathbb{R}^L$ for several two- and three-dimensional configurations. To this end, we compute the numerical sensitivity u_h^1 of the electric potential in the domain and the sensitivity U_h^1 of the measured voltages at electrodes (see (4.8) and (4.9) respectively) with respect to a small-amplitude perturbation in the conductivity. And we compute the numerical sensitivity u_h^2 of the electric potential in the domain and the sensitivity U_h^2 of the measured voltages at electrodes (see (4.13) and (4.14) respectively) with respect to a small perturbation in the contact impedance of some electrodes. This provides dimensionless qualitative indicators. The electric potential and the voltages are more impacted if the values of their sensitivity are high.

5.1. Numerical results in two dimensions

5.1.1. Set up

We consider three geometries: the unit disk, a head model, and a thorax (see Figure 1). The background conductivity in the unit disk is equal to $0.33S.m^{-1}$. The head model consists of three concentric disks with respective (dimensionless) radii $r_1 = 0.87$, $r_2 = 0.9$, and $r_3 = 1$ representing the three main tissues of the head: brain, skull, and scalp. Each layer is assumed to be homogeneous and isotropic. The adopted conductivity values are $\sigma_1 = \sigma_3 = 0.33S.m^{-1}$ for the brain and the scalp, respectively, and $\sigma_2 = 0.004S.m^{-1}$ for the skull. A CT scan of the thorax domain is obtained from [58]. Solving the CEM by means of finite elements requires the parametrization of the boundaries of the lungs, the heart, and the chest. These parametric curves are approximated using Fourier series. The coefficients of the Fourier series are estimated by finding the parametric curve that fits the data points on the boundary curve. With this, any practical domain or object may be studied for real-life applications of EIT. The background conductivity modeling the blood is set to $0.67S.m^{-1}$. The conductivities of the lungs and the heart are, respectively, fixed to $0.09S.m^{-1}$ and $0.4S.m^{-1}$ [44].

For the numerical simulations, $L = 32$ electrodes are attached around the boundary of the studied domain Ω (see Figure 2). The current pattern $I = (I_\ell)_\ell$ is defined by

$$I_\ell = \sin\left(\frac{2\pi\ell}{L}\right), \quad \ell = 0, 1, 2, \dots, L-1.$$

In order to impose the conservation of charge in real-life systems, when a current is injected through one electrode, its corresponding negative measure is injected through the opposite electrode. The

sine function satisfies this requirement in 2D set-up and [53] discussed in detail this choice of current pattern. All simulations are executed with the software FreeFem++ [29]. The different linear systems are solved with the default direct sparse solver in FreeFem++.

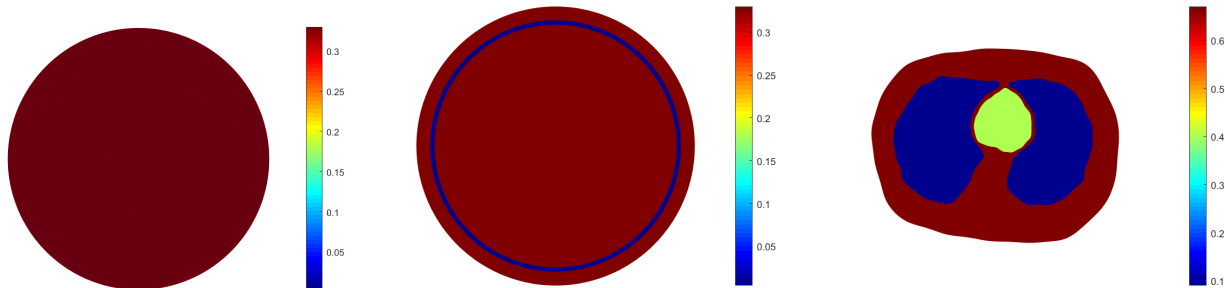


Figure 1. 2D geometries: a unit disk, a head model, and a thorax.

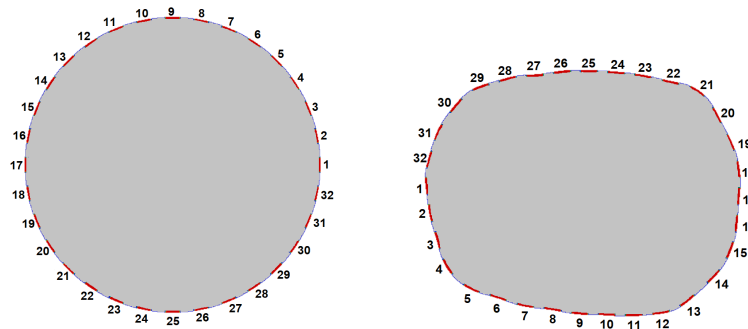


Figure 2. Location of the electrodes.

5.1.2. Sensitivity with respect to conductivity

The sensitivity (u_h^1, U_h^1) of the potential in the given direction μ is computed as the solution of the linear system (4.12) presented in Section 4. The contact impedance is set to be constant across all electrodes on the boundary, that is, $z_\ell = 0.1, \forall \ell = 0, \dots, L - 1$.

Unit disk. We consider a small-amplitude perturbation in the conductivity. This perturbation is modeled by a disk $D = D_r(\mathbf{x}_0)$ of radius r centred at \mathbf{x}_0 . The direction of the computed derivative is $\mu = \mathbf{1}_D$. A FEM mesh structure with 17 662 triangular elements and 8 992 nodes is used with mesh size $h = 0.038$. At the top of Figure 3, the perturbation of radius $r = 0.1$ is placed at two different positions, namely $\mathbf{x}_0 = (0.4, 0)$ (called configuration I) and $\mathbf{x}_0 = (0.7, 0)$ (called configuration II). In the bottom left of Figure 3, we report the sensitivity corresponding to the circular inhomogeneity centered at $\mathbf{x}_0 = (0.4, 0)$ for a bigger radius $r = 0.3$ (called configuration III). For each test-case, we report the map of the numerical sensitivity u_h^1 . The simulations indicate how the position of the inhomogeneity in the conductivity affects sensitivity. In particular, it shows that the largest values of the sensitivity are observed around the inhomogeneity and the sensitivity decreases away from the defect. Also, increasing the inhomogeneity's size increases the amplitude of the sensitivity significantly. Finally,

in the bottom right of Figure 3, we present the sensitivity corresponding to two circular perturbations (called configuration IV): one centered at $\mathbf{x}_0 = (0.4, 0)$ of radius $r = 0.1$ and the other centered at $\mathbf{x}_0 = (-0.4, -0.5)$ of radius $r = 0.2$.

To complete observations of Figure 3, Table 1 reports the sensitivity values U_h^1 of the voltages (i.e. of the EIT measurements) at some chosen electrodes. For configurations I and II, we have selected the electrodes e_4 and e_{30} which are located on the side of the conductivity perturbation, and the electrodes e_{13} and e_{17} which are on the opposite side. The sensitivity U_h^1 recorded at the electrodes near the inclusion, namely the components $U_h^1(4)$ and $U_h^1(30)$ at electrodes e_4 and e_{30} , has bigger values than at the ones far from it (i.e. the components $U_h^1(13)$ and $U_h^1(17)$ at electrodes e_{13} and e_{17}). A factor of 10 is observed. Thus the electrodes e_4 and e_{30} retain more information. Furthermore, as expected, the sensitivity U_h^1 becomes larger when the inclusion is very close to the boundary (Configurations II and IV) and when the inclusion is bigger in size (Configurations III and IV). Same conclusions are obtained in [62] using another definition of the sensitivity.

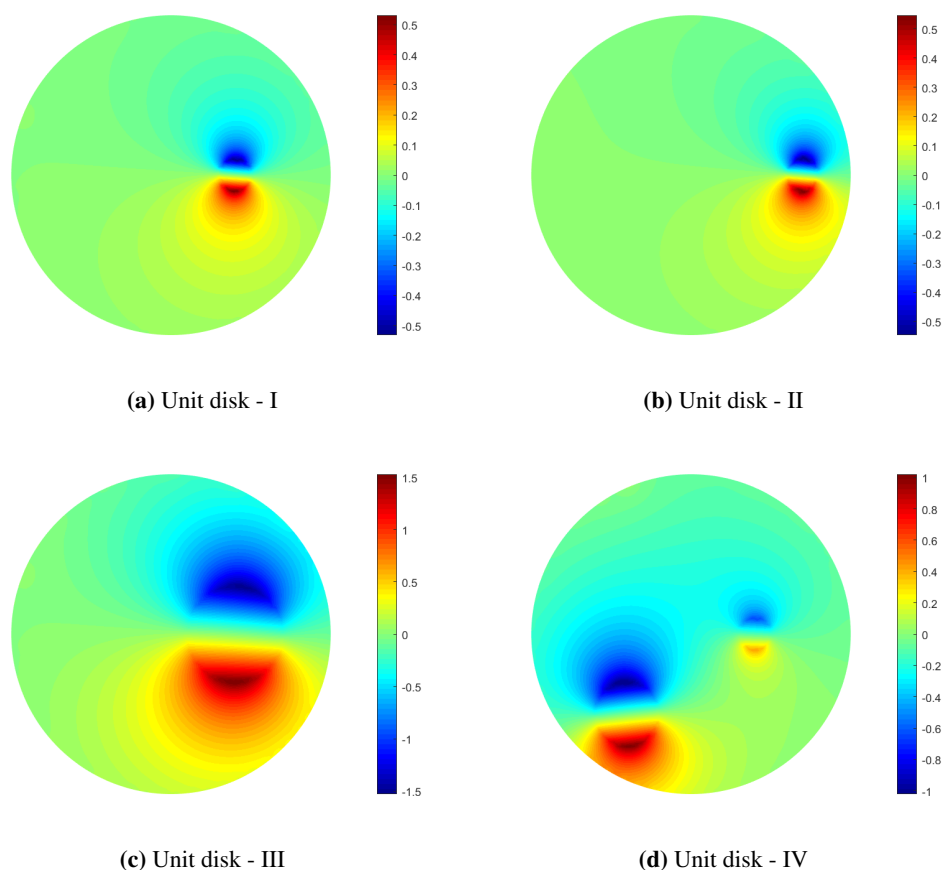
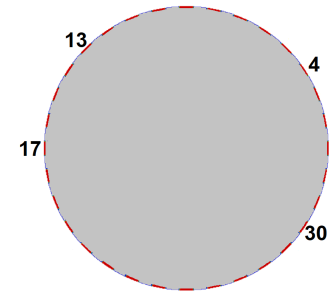


Figure 3. Unit disk. Numerical sensitivity u_h^1 of the electric potential with respect to the conductivity (Top left (Configuration I): $\mathbf{x}_0 = (0.4, 0)$, $r = 0.1$. Top right (Configuration II): $\mathbf{x}_0 = (0.7, 0)$, $r = 0.1$. Bottom left (Configuration III): $\mathbf{x}_0 = (0.4, 0)$, $r = 0.3$. Bottom right (Configuration IV): two disjoint perturbations, one is centered at $\mathbf{x}_0 = (0.4, 0)$ with radius $r = 0.1$ and the other is centered at $(-0.4, -0.5)$ with radius 0.2).

Table 1. Unit disk. Numerical sensitivity U_h^1 of the voltages with respect to conductivity at selected electrodes for the four configurations I-IV given in Figure 3.

Unit disk				
Electrode	I	II	III	IV
4	-0.0444	-0.0720	-0.4054	-0.0926
13	0.0003	0.0013	0.0036	0.0354
17	-0.0004	0.0023	-0.0046	-0.1593
30	0.0409	0.0737	0.3779	0.0040



Head model. First, we study the effect of a small perturbation in the conductivity of the region Ω_1 modeling the brain. The mesh characteristics are $h = 0.0368$, 17 952 triangular elements, and 9 137 nodes. Figure 4 compares the sensitivity map of the potential with respect to a perturbation of different locations and areas. We perform the same test-cases as for the unit disk (see Figure 3). We observe a similar behaviour of the sensitivity, with respect to the location, size, and number of perturbations. However, we note that there is a significant decrease in the sensitivity values for all the test-cases. The values of the sensitivity U_h^1 of the voltages on the boundary are close to zero (see Table 2). Nevertheless, here again the values are higher (factor of 10) at the electrodes which are on the side of the perturbation. The skull with a very small conductivity plays an important role in EIT. The adult skull is extremely resistive compared to the other tissues and acts as an electrical shield between the scalp and brain.

Now, we consider the configuration when only the skull conductivity is perturbed (i.e. $\mu = \mathbf{1}_{\Omega_2}$) and there is no perturbation in the brain. Figure 5 shows the sensitivity map in this case. Furthermore, the sensitivity values of the voltages at some electrodes for this simulation are given in Table 2 (last column). They are notably larger than the ones obtained from Configurations I-IV. It confirms that EIT measurements are highly sensitive to uncertainties in the value of the skull conductivity [20, 21].

Table 2. Head model. Numerical sensitivity U_h^1 of the voltages with respect to conductivity at selected electrodes for the four configurations I-IV given in Figure 4 and the one in Figure 5.

Head model					
Electrode	I	II	III	IV	skull
4	-0.0040	-0.0063	-0.0368	-0.0102	-45.80
13	0.0001	0.0002	0.0010	0.0025	0.6728
17	-0.0001	7.7E-05	-0.0012	-0.0139	-14.24
30	0.0034	0.0062	0.0314	0.0011	26.24

Thorax. The numerical sensitivity is computed on a mesh with characteristics: $h = 0.0428$, 18 450 triangular elements, and 9 386 nodes. Figure 6 shows the effect of a perturbation in the heart and the lungs conductivity on the sensitivity values. This perturbation may model a congenital cardiac defect or a pulmonary anomaly in the lungs, respectively. We observe that the interior electric potential is less sensitive to a presence of an anomaly (of the same size) in the heart than in the lungs. Furthermore, the largest values of the sensitivity of the boundary voltages are recorded at the electrodes which are close

to the perturbation (see Table 3).

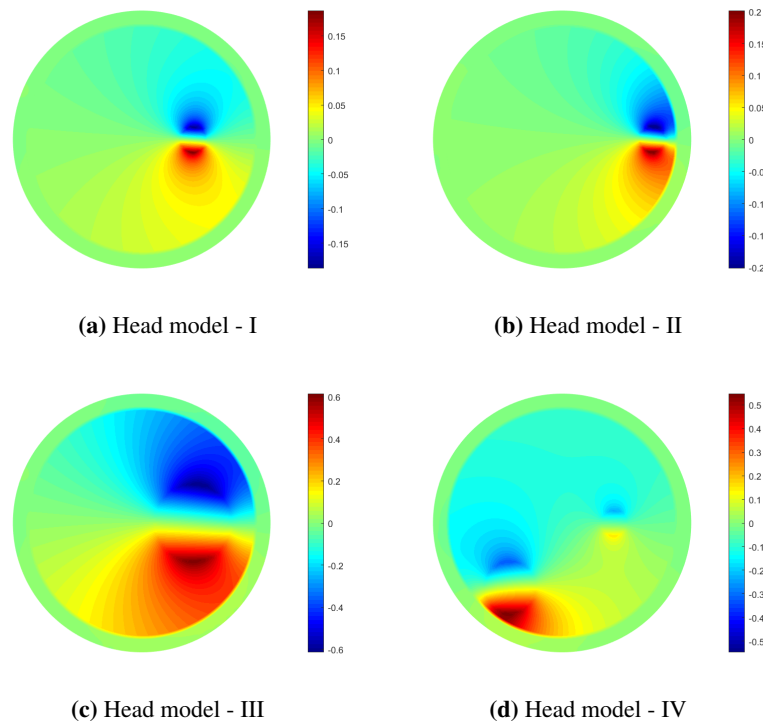


Figure 4. Head model. Numerical sensitivity u_h^1 of the electric potential with respect to the conductivity (Top left (Configuration I): $\mathbf{x}_0 = (0.4, 0)$, $r = 0.1$. Top right (Configuration II): $\mathbf{x}_0 = (0.7, 0)$, $r = 0.1$. Bottom left (Configuration III): $\mathbf{x}_0 = (0.4, 0)$, $r = 0.3$. Bottom right (Configuration IV): two disjoint perturbations, one is centered at $\mathbf{x}_0 = (0.4, 0)$ with radius $r = 0.1$ and the other is centered at $(-0.4, -0.5)$ with radius 0.2).

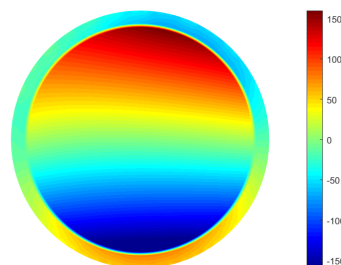


Figure 5. Numerical sensitivity u_h^1 of the electric potential when the skull conductivity is slightly perturbed.

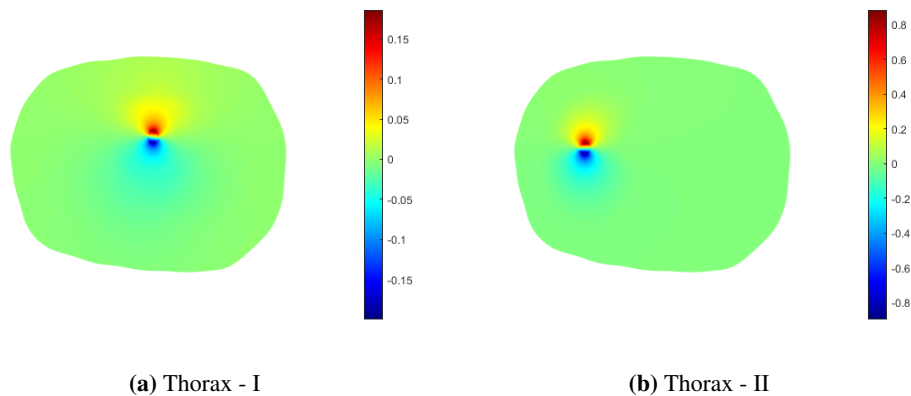
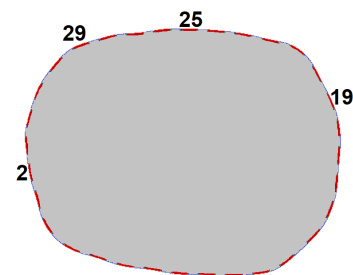


Figure 6. Thorax. Numerical sensitivity u_h^1 of the electric potential with respect to the conductivity. Left: perturbation inside the heart $\mathbf{x}_0 = (1.9, 1.75)$, $r = 0.05$. Right: perturbation inside the left lung $\mathbf{x}_0 = (1.25, 1.65)$, $r = 0.05$

Table 3. Thorax. Numerical sensitivity U_h^1 of the voltages with respect to conductivity at selected electrodes for the configurations I and II given in Figure 6.

Thorax		
Electrode	I	II
2	-0.0020	-0.0103
19	-0.0001	-0.0004
25	0.0101	0.0046
29	0.0017	0.0139



5.2. Numerical results in three dimensions

5.2.1. Set up

We consider two geometries: the unit ball and a spherical head model. In the unit ball, the background conductivity is fixed to $0.33S.m^{-1}$. The mesh size used for the unit ball is $h = 0.074$, for a total of 501 044 tetrahedrons and 87 817 nodes. As in 2D, the spherical head model consists of three concentric balls B_1 , B_2 and B_3 , and of respective radii $r_1 = 0.87$, $r_2 = 0.9$ and $r_3 = 1$ (see Figure 7). The regions $\Omega_1 = B_1$, $\Omega_2 = B_2 \setminus \Omega_1$ and $\Omega_3 = B_3 \setminus \Omega_2$ represent the brain, the skull, and the scalp, respectively. The values chosen for the conductivity of these tissues are the same as the 2D ones: $0.33S.m^{-1}$ for the brain and the scalp layers, and $0.004S.m^{-1}$ for the bone layer. The mesh uses 572 497 tetrahedrons and 99 546 nodes, ending up with a mesh size of $h = 0.074$.

We consider standard positioning for the electrodes and use the 10-10 system [22] (see Figure 7). This system gives us the spherical coordinates of the centers of $L = 71$ electrodes which are represented by small patches: the intersection of $\partial\Omega$ with a ball of radius 0.1. The contact impedance is the same on all electrodes and fixed to 0.1. For $\ell = 0, 1, \dots, L - 1$, the electrode e_ℓ is defined by the longitude

$\theta_\ell \in [0, 2\pi[$ and latitude $\varphi_\ell \in [-\pi/2, \pi/2]$ of its center. The current pattern I_ℓ on this electrode is set to

$$I_\ell = \sin \theta_\ell \cos \varphi_\ell, \quad \ell = 0, 1, \dots, L - 1.$$

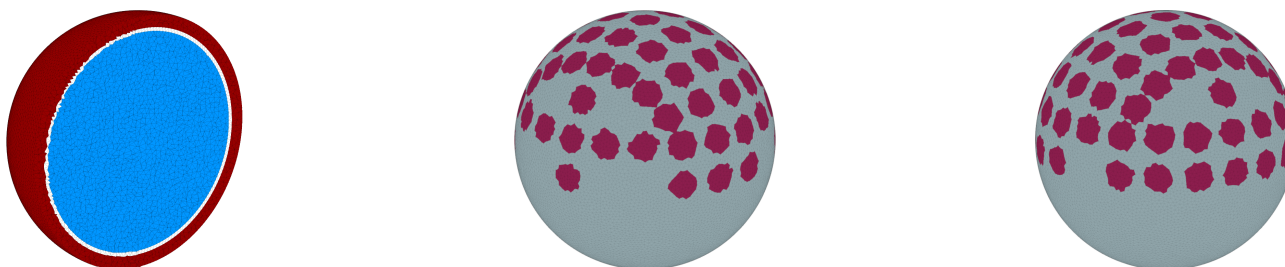


Figure 7. Left: layers of the spherical head model. Middle: front view of the 10-10 system for the electrodes positioning. Right: back view of the 10-10 system.

5.2.2. Sensitivity with respect to conductivity

We compute the numerical sensitivity (u_h^1, U_h^1) by solving the linear system (3.6) with direction μ set as the indicator function of the considered perturbation.

Unit ball. We first consider a spherical perturbation of center $(0.45, 0, 0.45)$ and of radius 0.2. We give on the top left of Figure 8 the sensitivity u_h^1 with respect to the conductivity in the direction corresponding to the indicator function of the ball. Top right and bottom of Figure 8 show the sensitivity in the direction of a perturbation centered at $(0, 0.3, 0.35)$. This perturbation is of radius 0.2 on the top right and of radius 0.35 on the bottom. As in 2D, we observe the largest values of the sensitivity around the support of the perturbation. Increasing the volume of the inhomogeneity increases the amplitude of the sensitivity.

Spherical head model. We run the same test-cases as for the unit ball. These three perturbations are all contained in the brain layer. The corresponding sensitivities are given in Figure 9. We observe the same behavior as with the unit ball if we look at the location of the biggest sensitivity values. However, the amplitude of these values is significantly lower here than in the unit ball because of the presence of the skull.

Surface measurements. The inverse problem we are interested in consists of the reconstruction of the conductivity inside the domain from the knowledge of the electrical potential values on the electrodes, which represent here the measurements. Assuming that the conductivity in healthy domains is known, this problem is equivalent to looking for inhomogeneities in this background parameter. Then, a similar argument to the one involved in [14] can be invoked: the Gâteaux derivative can be used to better understand the difference between the measurements on healthy and unknown domains.

In Figure 10, we show on the left the values of the numerical sensitivity on the boundary of the domain. On the right, we can observe the resulting values on the electrodes. Top of the figure is the case of a spherical perturbation centered at $(0, 0.3, 0.35)$ with radius 0.2. On the bottom, the perturbation is of same radius and centered at $(0, -0.3, 0.35)$. It appears that the highest absolute values of the surface measurements are located on the electrodes that are the nearest from the perturbation. The sign of these values seems to be governed by the sign of the injected current, which is the same as the sign of the y -coordinate. In fact, we observe that the positive part of the sensitivity is oriented to the part of the

boundary where a negative current is injected. This behavior matches the one we observed in the 2D simulations.

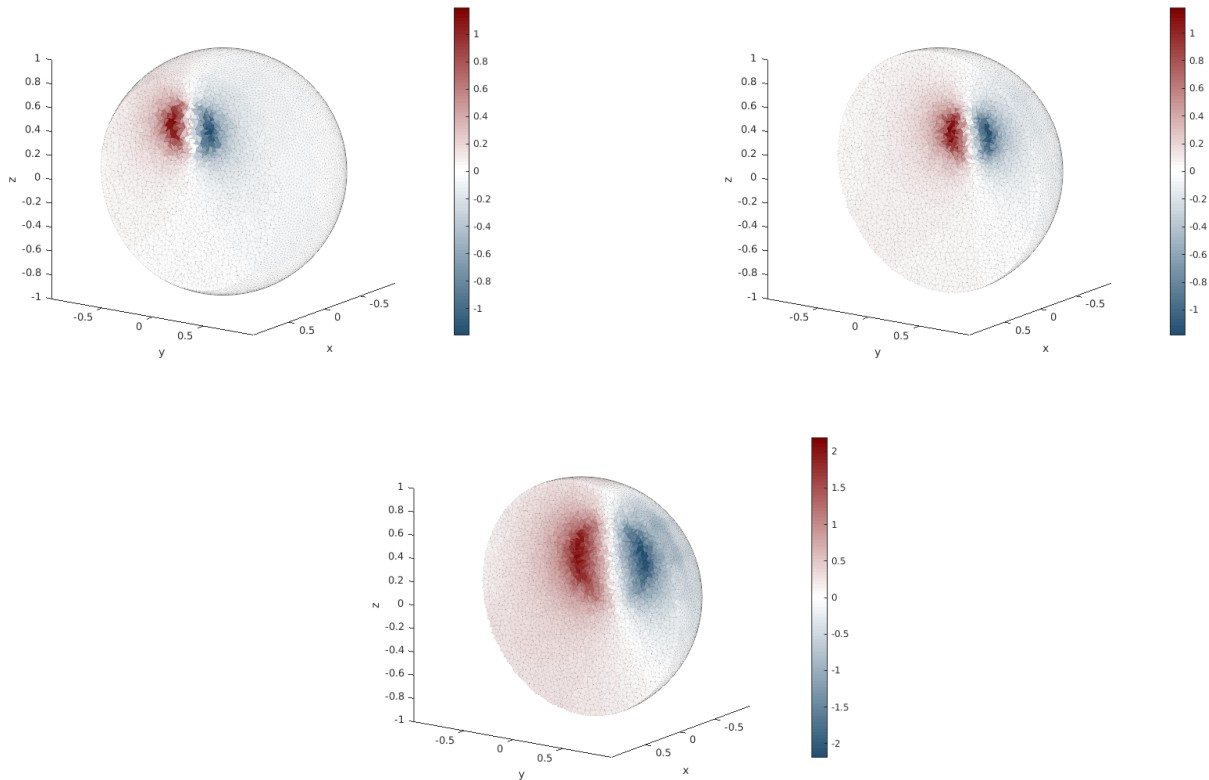


Figure 8. Numerical sensitivity u_h^1 of the electric potential with respect to the conductivity in the direction of the indicator function of the support of an inhomogeneity. Top left: centered at $(0.45, 0, 0.45)$ with radius 0.2. Top right: centered at $(0, 0.3, 0.35)$ with radius 0.2. Bottom: centered at $(0, 0.3, 0.35)$ with radius 0.35.

Remark 4. We can see that the conclusions are qualitatively similar for 2D and 3D configurations. Nevertheless, it seems easier to observe with eye the impact on the measurements in 3D. Thus, we report the numerical sensitivity of the potential with respect to contact impedance in 3D only, but keep the results in function of the conductivity in 2D and 3D for comparative purposes.

5.2.3. Sensitivity with respect to contact impedance

We compute the numerical sensitivity (u_h^2, U_h^2) by solving the linear system (3.10) with direction $\eta \in \{0, 1\}^L$: for $1 \leq \ell \leq L$, η_ℓ is set to 1 if we consider a perturbation on the ℓ -th electrode, and to 0 otherwise.

We model a small perturbation in the contact impedance of the 6th electrode, i.e. $\eta_\ell = 0$ for all $1 \leq \ell \leq L$ except for $\eta_6 = 1$. We show on the top left of Figure 11 the values of the sensitivity on the electrodes, i.e. the values of the vector U_h^2 . On the top right, we give the values of U_h^2 in the case of a perturbation on the 31st electrode. The bottom of this figure reports the values in the case of both the 6th and the 31st electrodes are perturbed.

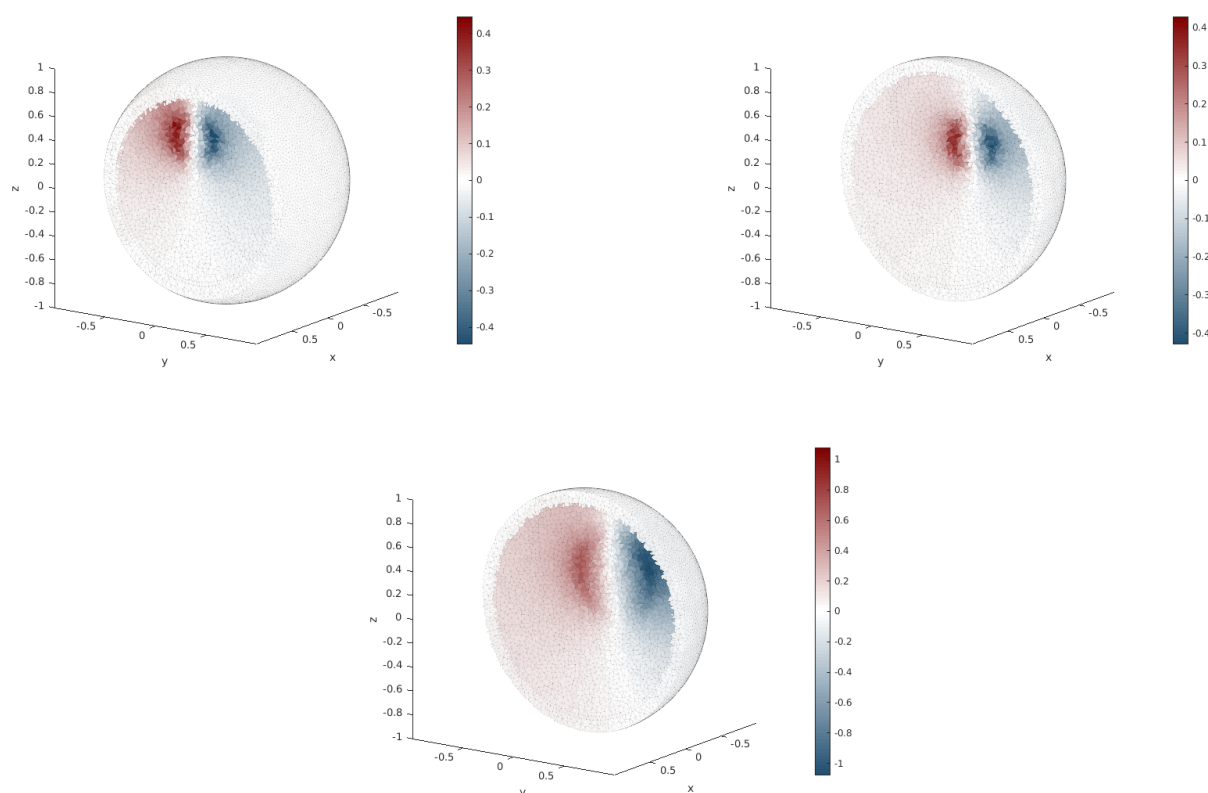


Figure 9. Numerical sensitivity u_h^1 of the electric potential with respect to the conductivity in the direction of the indicator function of the support of an inhomogeneity in the brain. Top left: centered at $(0.45, 0, 0.45)$ with radius 0.2. Top right: centered at $(0, 0.3, 0.35)$ with radius 0.2. Bottom: centered at $(0, 0.3, 0.35)$ with radius 0.35.

We first notice that a peak in the values of U_h^2 is easily visible: the highest amplitude is reached at the perturbed electrode. This behavior has been observed in all cases where a single electrode is perturbed. Moreover, the case of two perturbed electrodes indicate two peaks, each located at a perturbed electrode. It is in fact an illustration of the linearity of the sensitivity equation (3.10) with respect to the direction of differentiation: the vector η in the case of two perturbed electrodes is the sum of the two vectors corresponding to each electrode perturbed independently. Then, the sensitivities can also be summed to obtain the sensitivity corresponding to a perturbation of both electrodes.

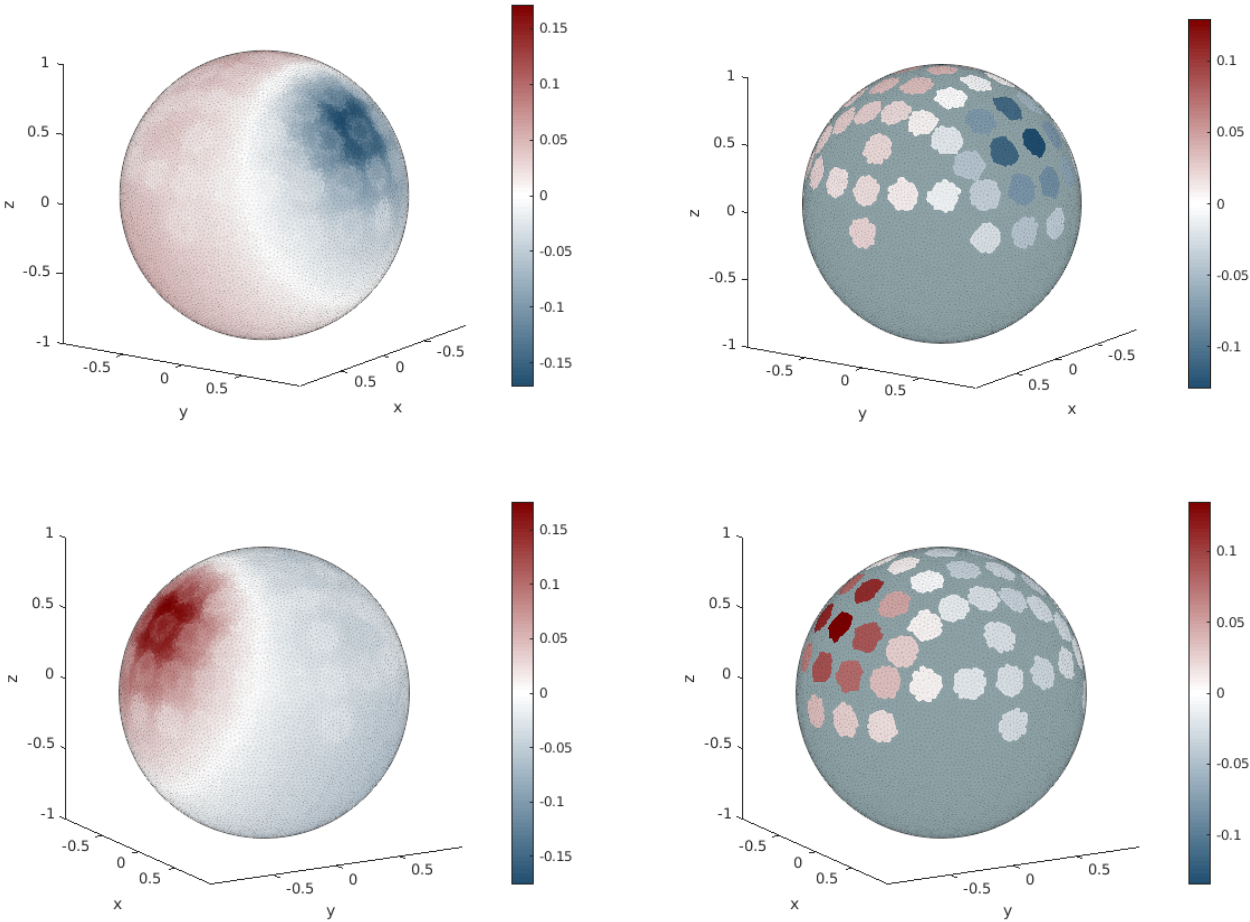


Figure 10. Boundary values of the sensitivity of the electric potential with respect to the conductivity in the direction of the indicator function of the support of a spherical inhomogeneity.

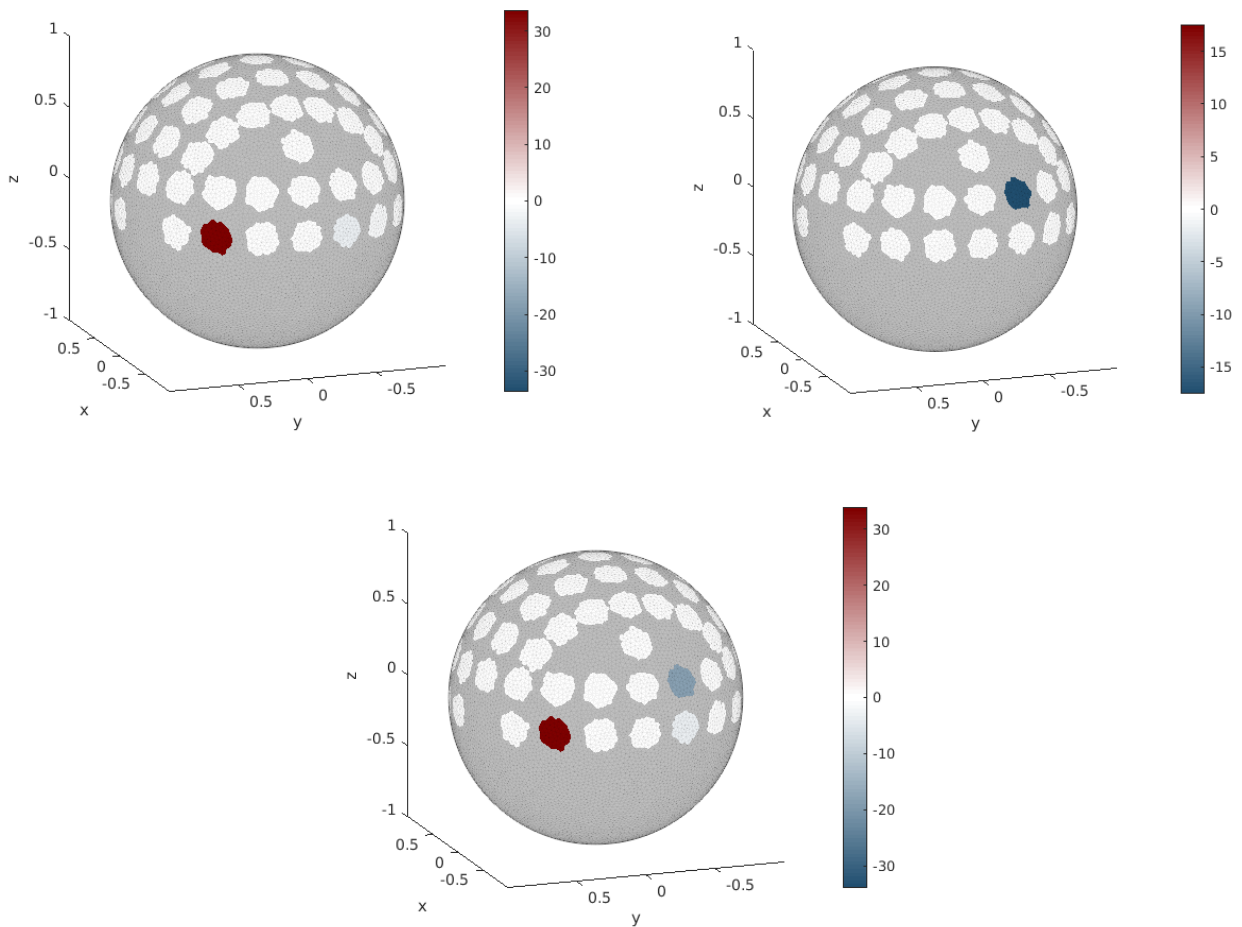


Figure 11. Boundary values of the numerical sensitivity of the electric potential with respect to the contact impedance in the direction of a small perturbation in the contact impedance of the 6th electrode (top left in red color), of the 31st (top right in blue color) and of both electrodes (bottom).

5.3. Sensitivity analysis and inverse conductivity problem

The previous numerical sensitivity analysis shows the effect of a perturbation in the conductivity or in the contact impedance of electrodes on the measured voltages $U = (U_\ell)_\ell \in \mathbb{R}^L$ which are the data of the EIT inverse problem. In particular, we have observed that a few number of electrodes only are sensitive with respect to a small-amplitude perturbation in the conductivity medium and the impact depends on both the size and location of the inclusion. This section gives some first numerical simulations that confirm that the reconstruction process can be affected if the information recorded by those electrodes is missing.

To this end, we consider a domain Ω containing one inclusion. The background conductivity of the medium and the geometric characteristics of the inclusion are assumed to be known. We would like to estimate the conductivity value σ_p inside the perturbation. To solve this inverse problem, we reformulate it into a minimization problem in \mathbb{R} . Then we minimize numerically the cost functional using the Broyden-Fletcher-Goldfarb-Shanno (BFGS) method, which is a gradient-based optimization algorithm. No regularization is applied. It was shown numerically in [57] that the BFGS algorithm is effective in solving the inverse EIT problem if the supports of the inclusions are known. We compare the numerical approximation of σ_p for different configurations: measurements taken on all the electrodes or on some of them only, perturbation in the contact impedance of some electrodes.

5.3.1. Numerical set-up

Let Ω be the unit disk with a (fixed) circular inclusion Ω_p centered at $(0.7, 0)$ with radius $r = 0.1$. This is Configuration II tested in Section 5.1.2. We work with synthetic data that are generated setting a background conductivity $\sigma_b = 0.33S.m^{-1}$ and a conductivity $\sigma_p = 0.4S.m^{-1}$ inside the inclusion. The contact impedance is constant across L electrodes and it is equal to $z_\ell = 0.1$, $\ell = 0, \dots, L - 1$ (unless indicated otherwise). To obtain the voltage data $U_{obs}^j \in \mathbb{R}^L$, $j = 1, \dots, 16$, sixteen current patterns are applied on the electrodes and the first current has the form

$$I^1 = \{I_\ell^1\}_{\ell=0}^{L-1} = \sin \theta_\ell.$$

The remaining fifteen current patterns are obtained by ‘rotating’ the values of the first current pattern, that is, to get the second current pattern I^2 , we have $I^2(0) = I^1(L - 1)$, $I^2(1 : L/2) = I^1(0 : L/2 - 1)$, and $I^2(L/2 + 1 : L - 1) = I^1(L/2 : L - 2)$. This is repeated until we obtain the fifteen additional current patterns. A 1% additive noise is applied to the data (compare with [31, 57]). For the numerical resolution of the forward CEM, an FEM mesh structure with 25 858 triangular elements, 13 122 nodes, and mesh size 0.0115 was used, while a different mesh system with 17 882 triangular elements, 9 102 nodes, and mesh size 0.0138 was adopted for the inversion method. We implemented the numerical solver for the forward problem (4.7) with FreeFem++ [29]. The inverse conductivity problem is reformulated as the minimization of the following cost functional $J : \mathbb{R} \rightarrow \mathbb{R}$

$$J(\tilde{\sigma}) = \frac{1}{2} \sum_{j=1}^{16} \|U^j(\sigma) - U_{obs}^j\|_2^2, \quad (5.1)$$

where the voltages $U^j(\sigma) \in \mathbb{R}^L$ are obtained by solving the forward CEM (2.4)-(2.7)-(2.8)-(2.9) with the conductivity distribution σ (σ_b in the background $\Omega \setminus \overline{\Omega_p}$ and $\tilde{\sigma}$ inside the inclusion Ω_p) and the current pattern I^j . The minimization is done in MATLAB using the built-in command for BFGS algorithm, *fminunc*. Tolerance is set to be the default ($\epsilon = 1E-06$). Initial guess is set to $\tilde{\sigma}^0 = 0.6 S.m^{-1}$.

5.3.2. Numerical results

Recall that we have observed in Section 5.1.2 that the sensitivity U_h^1 of the voltages with respect to a small-amplitude perturbation in the conductivity has higher values on the electrodes 1-8 and 25-32 (see Configuration II Figure 3 and Table 1). Supposedly, these electrodes contain the main information for the reconstruction process. On the contrary, the sensitivity values U_h^1 on electrodes 9-24 are small or almost zero. This inspires us three first set-ups for the numerical resolution of the inverse problem:

- A. The voltages are recorded on the $L = 32$ electrodes (see Figure 1 left).
- B. We keep only the sixteen values of the voltages on electrodes 1-8 and 25-32 (see Figure 12 left) which are located on the side of the inclusion.
- C. We keep only the sixteen values of the voltages on electrodes 9-24 (see Figure 12 right) which are located on the opposite side of the inclusion.

Furthermore, we have seen that the voltages are sensitive to a small change in the contact impedance of electrodes and the impact is localized on the electrodes which are perturbed. It is interesting to observe the effect of such a small variation in the contact impedance of some electrodes on the numerical resolution of the inverse problem. We add two set-ups. The data are recorded on all the $L = 32$ electrodes.

- D. We set $z = 0.07$ for electrodes 1-8 and 25-32 and $z = 0.1$ for the rest.
- E. We set $z = 0.07$ for electrodes 9-24 and $z = 0.1$ for the rest.

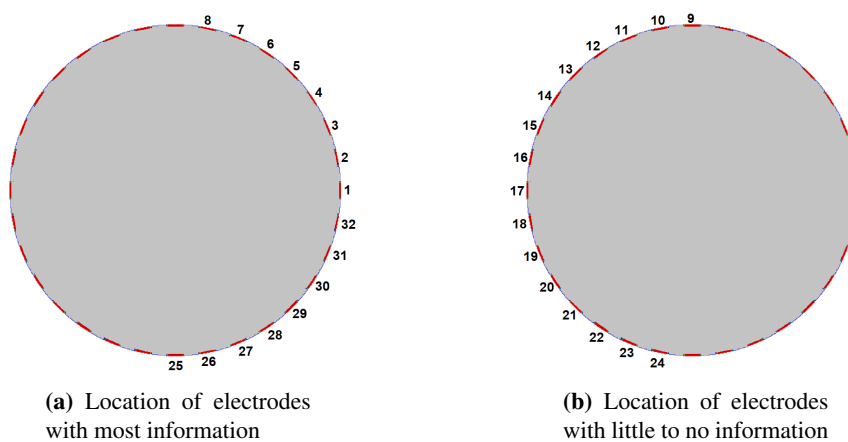


Figure 12. Unit disk with fixed circular inclusion. Location of electrodes that contain the most information about the perturbation (left) and electrodes that have little to no information (right).

We report on Figure 13 the numerical reconstruction of the conductivity for the different set-ups, and in Table 4 the corresponding approximations of σ_p and relative errors. In agreement with the numerical sensitivity analysis, the accuracy deteriorates when the EIT measurements on the electrodes located on the side of the inclusion are missing. Set-up C leads to an error of 35% against 8% for Set-up B which considers only the electrodes on the side of the inclusion. This confirms that those electrodes contain the essential data for the reconstruction process. Furthermore, Set-ups D and E illustrate that the accuracy of the reconstruction depends on the contact impedance of the electrodes too. This first

study attests that the sensitivity analysis for the CEM leads to a very good understanding of the link between the parameters of the model and the EIT measurements . We will give in the last part the conclusions and the perspectives these numerical results suggest.

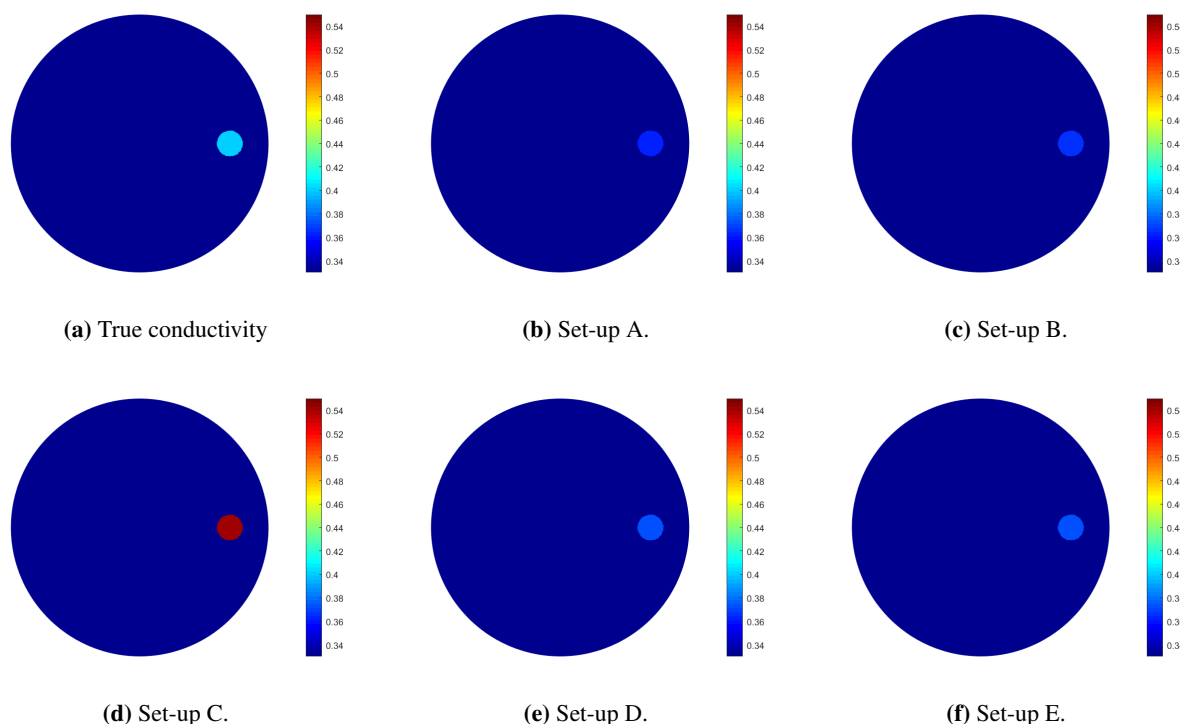


Figure 13. Unit disk with a fixed circular inclusion. Numerical estimation of the conductivity value inside the circular inclusion by solving the minimization problem (5.1) for set-ups A.-E.

Table 4. Unit disk with a fixed circular inclusion. Numerical estimation of the conductivity value inside the inclusion: approximated conductivity and relative error.

		Unit disk				
	True	A.	B.	C.	D.	E.
Approximation	0.4	0.3626	0.3671	0.5426	0.3731	0.3743
Relative error		0.0934	0.0822	0.3566	0.0670	0.0640

6. Conclusion and future works

In this work, we proposed a sensitivity analysis of both the interior electric potential and the EIT measurements with respect to small changes in conductivity inside an object or in contact impedance of the surface electrodes. We thoroughly studied the sensitivity of the electric potential using its Gâteaux differentiability in the theoretical and numerical point of view. We conclude that the useful information for the inversion process in EIT is essentially contained on a small part of the boundary, that is, at the electrodes close to the perturbations in the conductivity. The boundary measurements, which

are the data for the inverse conductivity problem, are more sensitive to anomalies that are located near the boundary and to those that are larger in size. This study is insightful to know the critical parameter values (size, location) of a small-amplitude perturbation in the conductivity under which the measurements are not sensitive, and hence under which inhomogeneities could not be detectable. We have also observed in the head model that an uncertainty of a tissue conductivity value could have a great impact on the measurements, and by consequence on the EIT reconstruction.

Furthermore, we have shown that the sensitivity of the measurements to a small perturbation in the electrode-skin interface is localized on the faulty electrode. By linearity, when the contact impedance of another electrode is a little bit perturbed, the total sensitivity is the sum of the corresponding sensitivities. This could be damageable for the EIT conductivity reconstruction if those electrodes are located on the side of the sought inclusions. This observation is in agreement with other works which propose to reconstruct the electrode contact impedance as part of the EIT inverse problem [7,17,30,59].

Sensitivity analysis is very instructive to understand how EIT detects changes in inhomogeneous media with and without anomaly. It would be interesting to explicitly define the relations between the sensitivity values and the characteristics of the perturbations as in [14, 62]. More precisely, one of our objectives is to find explicit relations between the EIT measurements and the geometric parameters (center, volume, ...) of the inclusions. To know the supports of the inclusions could give good initial guesses for an iterative reconstruction process. For instance, this would allow to retrieve with a good accuracy the value of the conductivity inside the inclusions as we have seen in Section 5.3. The first reconstruction tests presented in this work are promising but this is a full-fledged research project which needs more time and investigation. This is beyond the scope of this paper. Although shape derivative has been used in several studies to reconstruct conductivity distribution in EIT [1, 31, 48, 55] but to our knowledge, a rigorous sensitivity analysis with respect to the shape of the electrode has not been done. Finally, another conclusion of our study is that the essential data for the inverse conductivity problem are contained in a few number of electrodes. The accuracy deteriorates if those electrodes (and thus this part of the boundary) are not taken into account. To be sure not to miss this main information, data completion methods [5, 13] could be a possible way to get the values of the voltages on all the boundary of the object under inspection. These are interesting future research directions which require comprehensive separate studies.

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Conflict of interest

The authors declare there is no conflict of interest in this paper.

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Appendix: Proof of Proposition 2

Proof. Let (u, U) be the solution in H of the variational problem (2.12). Suppose that $Z = (z_\ell)_{\ell=1}^L \in \mathcal{Z}_{\text{adm}}$, $h > 0$, and $\eta \in \mathbb{R}^L$ such that $\tilde{Z} := Z + \eta h \in \mathcal{Z}_{\text{adm}}$. Let $(\tilde{u}^h, \tilde{U}^h)$ the solution in H of the perturbed CEM forward problem with contact impedance \tilde{Z} . The corresponding variational problem reads as follows: find $(\tilde{u}^h, \tilde{U}^h) \in H$ such that

$$B_{\tilde{Z}}((\tilde{u}^h, \tilde{U}^h), (w, W)) = \sum_{\ell=1}^L I_\ell W_\ell \quad (6.1)$$

for all $(w, W) \in H$, where the bilinear form is defined by

$$B_{\tilde{Z}}((\tilde{u}^h, \tilde{U}^h), (w, W)) := \int_{\Omega} \sigma \nabla \tilde{u}^h \cdot \nabla w \, d\mathbf{x} + \sum_{\ell=1}^L \frac{1}{z_\ell + \eta_\ell h} \int_{e_\ell} (\tilde{u}^h - \tilde{U}_\ell^h)(w - W_\ell) \, ds. \quad (6.2)$$

Subtracting (2.12) from (6.1) and dividing by h , we have

$$\int_{\Omega} \sigma \nabla \left(\frac{\tilde{u}^h - u}{h} \right) \cdot \nabla w \, d\mathbf{x} + \sum_{\ell=1}^L \int_{e_\ell} \left(\frac{1}{h} \left(\frac{\tilde{u}^h}{z_\ell + h\eta_\ell} - \frac{u}{z_\ell} \right) - \frac{1}{h} \left(\frac{\tilde{U}_\ell^h}{z_\ell + h\eta_\ell} - \frac{U_\ell}{z_\ell} \right) \right) (w - W_\ell) \, ds = 0. \quad (6.3)$$

A Taylor expansion yields

$$\frac{1}{z_\ell + h\eta_\ell} = \frac{1}{z_\ell} - h \frac{\eta_\ell}{z_\ell^2} + \mathcal{O}(h^2),$$

from which we deduce

$$\frac{1}{h} \left(\frac{\tilde{u}^h}{z_\ell + h\eta_\ell} - \frac{u}{z_\ell} \right) = \frac{1}{z_\ell} \frac{\tilde{u}^h - u}{h} - \frac{\eta_\ell}{z_\ell^2} \tilde{u}^h + \mathcal{O}(h).$$

Now, the differential quotients defined by

$$u^{h,2} := \frac{\tilde{u}^h - u}{h} \quad \text{and} \quad U^{h,2} := \frac{\tilde{U}^h - U}{h}$$

satisfy the variational formulation

$$B_{\sigma}((u^{h,2}, U^{h,2}), (w, W)) = \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} (\tilde{u}^h - \tilde{U}_\ell^h)(w - W_\ell) \, ds + \mathcal{O}(h) \quad (6.4)$$

for all $(w, W) \in H$. Furthermore, suppose $(u^2, U^2) \in H$ is the solution to the variational problem (3.10) i.e.

$$B_{\sigma}((u^2, U^2), (w, W)) = \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} (u - U_\ell)(w - W_\ell) \, ds$$

for all $(w, W) \in H$. Next, subtracting (3.10) from (6.4), we obtain

$$B_{\sigma}((u^{h,2} - u^2, U^{h,2} - U^2), (w, W)) = \sum_{\ell=1}^L \frac{\eta_\ell}{z_\ell^2} \int_{e_\ell} ((\tilde{u}^h - u) - (U_\ell^h - U_\ell))(w - W_\ell) \, ds + \mathcal{O}(h).$$

Take $(w, W) = (u^{h,2} - u^2, U^{h,2} - U^2)$. From the continuity and coercivity of the bilinear form B_σ , and using the equivalence of norms, we get

$$\|(u^{h,2} - u^2, U^{h,2} - U^2)\|_* \lesssim \|\eta\|_\infty \|(\tilde{u}^h - u, \tilde{U}^h - U)\|_* + \mathcal{O}(h) \quad (6.5)$$

where $\|\eta\|_\infty := \max_{1 \leq \ell \leq L} |\eta_\ell|$. In the same way, we set $(w, W) = (\tilde{u}^h - u, \tilde{U}^h - U)$ in (6.4) and we get

$$\|(\tilde{u}^h - u, \tilde{U}^h - U)\|_* \lesssim h \|\eta\|_\infty \|(\tilde{u}, \tilde{U})\|_* + \mathcal{O}(h^2)$$

and hence

$$\|(u^{h,2} - u^2, U^{h,2} - U^2)\|_* \lesssim h \|\eta\|_\infty^2 + \mathcal{O}(h^2).$$

This proves the strong convergence of $(u^{h,2}, U^{h,2})_h$ to (u^2, U^2) .

Lastly we prove that the map $\eta \mapsto (u^2, U^2)$ is linear continuous from \mathbb{R}^L to H . Since (u^2, U^2) is defined by (3.10) and the right-hand side of (3.10) is linear in η , the map is also linear in η . Taking $(w, W) = (u^2, U^2)$ in (3.10), the continuity of the bilinear form gives us the following estimate

$$\|(u^2, U^2)\|_* \lesssim \|\eta\|_\infty.$$

This ends the proof of the Gâteaux differentiability of the CEM forward solution with respect to the contact impedance. \square



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